SPICE Device Model Si4490DY



Vishay Siliconix

N-Channel 200 V (D-S) MOSFET

DESCRIPTION

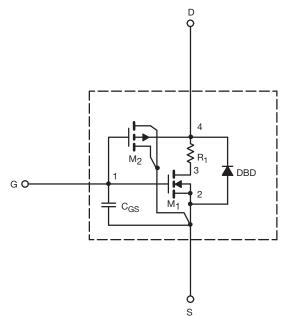
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to 125 °C temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	3	-	V
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \geq 5 \text{ V}, V_{GS} = 10 \text{ V}$	74	-	А
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 4 \text{ A}$	0.068	0.065	Ω
		$V_{GS} = 6 V$, $I_D = 4 A$	0.072	0.070	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 5 \text{ A}$	23	19	S
Diode Forward Voltage ^a	V _{SD}	$I_{\rm S}$ = 2.8 A, $V_{\rm GS}$ = 0 V	0.76	0.75	V
Dynamic ^b					
Total Gate Charge	Qg	V_{DS} = 100 V, V_{GS} = 10 V, I_D = 4 A	35	34	nC
Gate-Source Charge	Q _{gs}		7.5	7.5	
Gate-Drain Charge	Q _{gd}		12	12	
Turn-On Delay Time	t _{d(on)}	V_{DD} = 100 V, R _L = 25 Ω I _D = 4 A, V _{GEN} = 10 V, R _g = 6 Ω I _F = 2.8 A, dl/dt = 100 A/µs	27	14	ns
Rise Time	t _r		39	20	
Turn-Off Delay Time	t _{d(off)}		39	32	
Fall Time	t _f		55	25	
Source-Drain Reverse Recovery Time	t _{rr}		70	70	

Notes

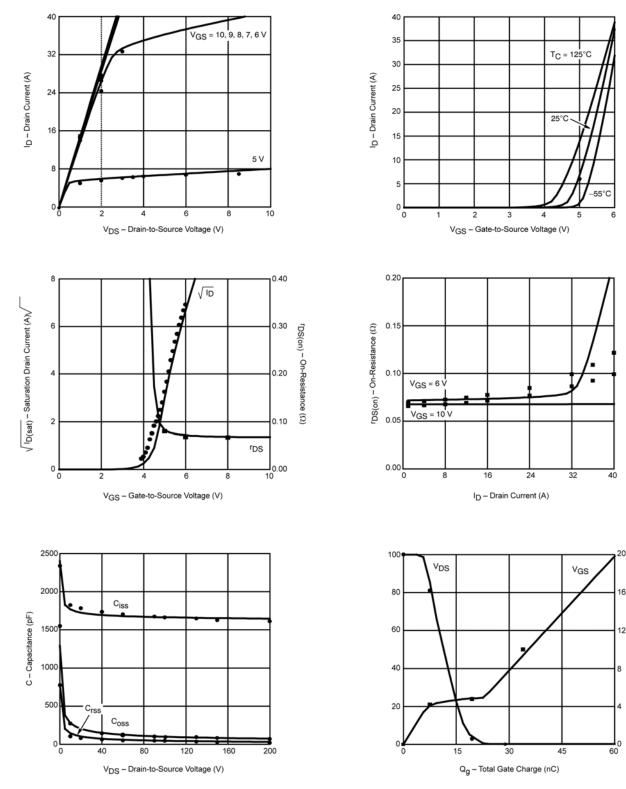
a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.



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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)



Note

• Dots and squares represent measured data.

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